



120V NPN DARLINGTON TRANSISTOR IN SOT223

Features

- BV_{CEO} > 120V
- BV_{CBO} > 140V
- I_C = 1.5A High Continuous Current
- hFE > 2k for High Gain @ 1A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

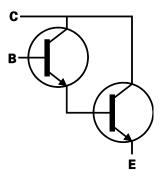
Applications

- Lamp
- Relay
- Solenoid Driving

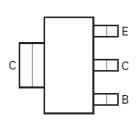
SOT223 (Type DN)



Top View



Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

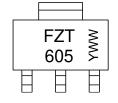
Part Number	Compliance	Package	Marking Reel Size (inches) Tape Width (mm)		king		
Fait Nullibei	Number Compliance Fackage Marking		neer Size (Inches)	rape widin (ililii)	Qty.	Carrier	
FZT605TA	Standard	SOT223 (Type DN)	FZT605	7	12	1,000	Reel
FZT605TC	Standard	SOT223 (Type DN)	FZT605	13	12	4,000	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223 (Type DN)



FZT605 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or $\overline{W}W$ = Week Code (01 to 53)



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	140	V
Collector-Emitter Voltage	V_{CEO}	120	V
Emitter-Base Voltage	V _{EBO}	14	V
Continuous Collector Current	lc	1.5	Α
Peak Pulse Current	Ісм	4	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)	PD	3.0	
Dower Discipation	(Note 6)		2.0	□ w
Power Dissipation	(Note 7)		1.6	vv
	(Note 8)		1.2	
	(Note 5)		41.7	
Thermal Desigtance, Junction to Ambient	(Note 6)	- Raia	62.5	
Thermal Resistance, Junction to Ambient	(Note 7)		78.1	°C/W
	(Note 8)		104	
Thermal Resistance Junction to Lead (Note 9)		R ₀ JL	12.9	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 10)

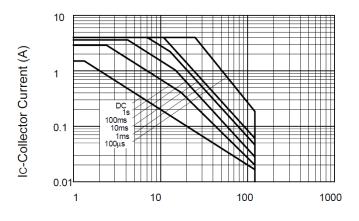
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

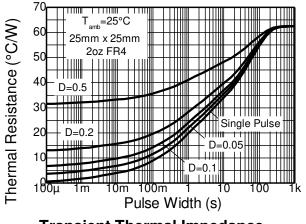


Thermal Characteristics and Derating Information

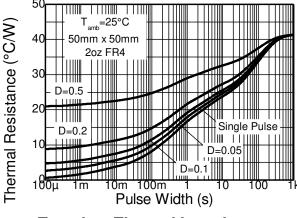


VCE - Collector Emitter Voltage (V)

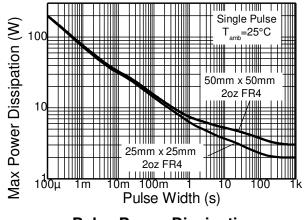
FZT605 Safe Operating Area



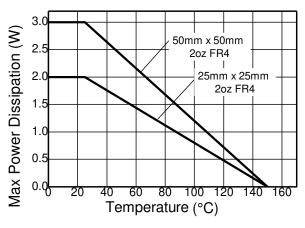
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	140	-	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BVceo	120	_	_	V	Ic = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	14	_	_	V	I _E = 100μA
Collector-Base Cut-Off Current	Ісво	_	_	100 10	nA μA	V _{CB} = 120V V _{CB} = 120V, T _A = +120°C
Collector-Emitter Cut-Off Current	Ices	_	_	100	nA	V _{CE} = 120V
Emitter Cut-Off Current	I _{EBO}	_	_	100	nA	V _{EB} = 8V
DC Current Gain (Note 11)	hFE	2,000 5,000 2,000 500	1111	 100,000 	_	IC = 50mA, VCE = 5V IC = 500mA, VCE = 5V IC = 1A, VCE = 5V IC = 2A, VCE = 5V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	_	_	1 1.5	V	$I_C = 250$ mA, $I_B = 0.25$ mA $I_C = 1$ A, $I_B = 1$ mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	_	_	1.8	V	Ic = 1A, I _B = 1mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	_	_	1.7	V	Ic = 1A, VcE = 5V
Input Capacitance	Cibo	_	90	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	_	15	_	pF	V _{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	fτ	150	_	_	MHz	V _{CE} = 10V, I _C = 100mA f = 20MHz
Turn-On Time	ton	_	0.5	_	μs	V _{CC} = 10V, I _C = 500mA
Turn-Off Time	toff	_	1.6	_	μs	$I_{B1} = -I_{B2} = 0.5 \text{mA}$

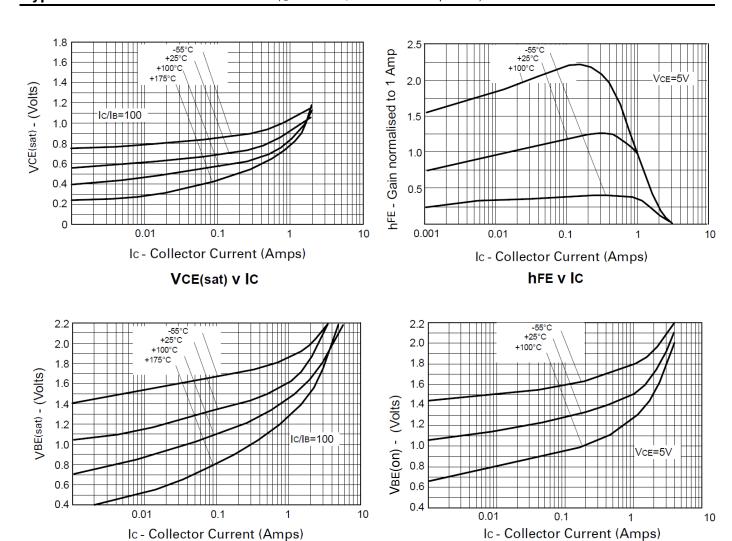
Note: 11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

VBE(on) v IC



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

VBE(sat) v IC

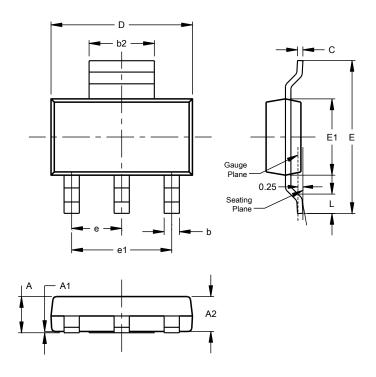




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

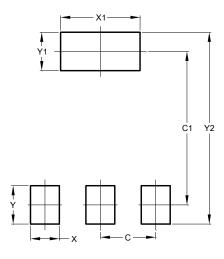


SOT223 (Type DN)						
Dim	Min	Max	Тур			
Α		1.70				
A1	0.01	0.15				
A2	1.50	1.68	1.60			
b	0.60	0.80	0.70			
b2	2.90	3.10				
С	0.20	0.32				
D	6.30	6.70				
Е	6.70	7.30				
E1	3.30	3.70				
е			2.30			
e1			4.60			
L	0.85					
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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